

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1683	(carbon with (nano\$1tube)) same semiconductor\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 08:23
L2	528	1 and (@ad or @rlad) < "20021105"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 08:24
L3	59	2 and (nano\$1tube) with (dop\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 08:32
L4	59	2 and (nano\$1tube with dop\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 08:32
L5	69	2 and (nano\$1tube with junction)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 08:35
L6	269	((silicon or Si) near2 nano\$1tube)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 08:47
L7	74	6 and (@ad or @rlad) < "20021105"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 08:51
L8	707	(nano\$1tube with (crystal or crystallin\$3 or mantle))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 08:56

L9	239	8 and (@ad or @rlad) < "20021105"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 08:56
L10	873	(nano\$tube with solvent)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 09:49
L11	178	(dispersion with nano \$tube with solvent)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 09:49
L12	42	11 and (@ad or @rlad) < "20021105"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 09:50
L13	358	(nano\$tube near3 fill \$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 10:36
L14	162	13 and (@ad or @rlad) < "20021105"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 10:37
L15	44	(nanotube with hollow with (Si or silicon or semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 11:05
L16	21	15 and (@ad or @rlad) < "20021105"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 11:06
L17	149	(nanotube with fill\$3 with (Si or silicon or semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 11:11

L18	48	17 and (@ad or @rlad) < "20021105"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 11:11
L19	2	(nanotube with ((pn or "p-n") near2 junction)) and (nanotube with dispersion)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 11:36
L20	57	(nanotube with ((pn or "p-n") near2 junction))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 11:40
L21	14	20 and (@ad or @rlad) < "20021105"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 11:41
L22	6	(nanotube with (insulat \$3 with por\$3)) and (nanotube with dispersion)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 12:15
L23	8	(nanotube with (insulat \$3 with por\$3)) and (nanotube with (dispers \$3 or solvent))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 12:20
L25	231	257/e51.04.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/13 15:33
S1	289	(InP or (compound near2 semiconduct\$3)) with (nanotube or nanowire)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 03:01
S2	96	S1 and (@ad or @rlad) < "20021105"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 17:31

S3	73	S2 and (crystal\$4 with (nanotube or nanowire))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 16:34
S4	6	"533509".ap.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 03:26
S5	58397	"3" and ((hollow or empty) with core)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 16:35
S6	289	(InP or (compound near2 semiconduct\$3)) with (nanotube or nanowire)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 17:08
S7	96	S6 and (@ad or @rlad) < "20021105"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 17:01
S8	73	S7 and (crystal\$4 with (nanotube or nanowire))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 16:35
S9	2	S8 and ((hollow or empty) with core)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 16:48
S10	30	S7 and hollow	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 16:48
S11	2	(InP with nano\$1tube) and (nano\$1tube with diameter) and junction and hollow	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 17:12

S12	56	(semiconduct\$3 with nano\$1tube) and (nano\$1tube with diameter) and junction and hollow	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 17:26
S13	37	S12 and (@ad or @rlad) < "20021105"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 17:13
S14	34	((InP or GaAs or (semiconduct\$3 near2 compound)) with (nanowire or nano\$1tube) and ((nanowire or nanostructure) with hollow) and junction and diameter	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 17:27
S15	13	S14 and (@ad or @rlad) < "20021105"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/07/13 17:31
S16	1373	(semiconduct\$3) near3 (nanotube or (nano near tube))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/06 10:58
S17	440	S16 and (@ad or @rlad) < "20021105"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/06 10:59
S18	35	("III-V" with nanotube)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/06 11:29
S19	13	S18 and (@ad or @rlad) < "20021105"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/08/06 11:29

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